



Data Sheet

MOSFET, N CHANNEL, 30V, 0.0049OHM, 15A, Transistor Polarity:N Channel, Continuous Drain Current Id:15A, Drain Source Voltage Vds:30V, On Resistance Rds(on):0.0049ohm, Rds(on) Test Voltage Vgs:10V, Threshold Voltage Vgs:1.2V

Manufacturers

ON Semiconductor, LLC

Package/Case

SOIC-8

Product Type

Transistors

Green

Lifecycle

**RoHS** 



Images are for reference only

Please submit RFQ for FDS8896 or Email to us: sales@ovaga.com We will contact you in 12 hours.

<u>RFQ</u>

## **General Description**

This N-Channel MOSFET has been designed specifically to improve the overall efficiency of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low rDS(ON) and fast switching speed.

Features Application

RoHS Compliant ONSEMI



## **Related Products**



**FDC645N** 

ON Semiconductor, LLC SSOT-6



**FDC6305N** 

ON Semiconductor, LLC SSOT-6



**FDD8647L** 

ON Semiconductor, LLC TO-252-3



FDD5N50NZTM

ON Semiconductor, LLC TO-252



FDC637BNZ

ON Semiconductor, LLC SSOT-6



**FDC602P** 

ON Semiconductor, LLC SOT163



**FDB070AN06A0** 

ON Semiconductor, LLC TO-263



**FDD3670** 

ON Semiconductor, LLC TO-252AA